## NSN 5961-00-881-0335

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Inclosure Material:
Metal
Overall Length:
0.550 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 0.740 inches and 0.760 inches
Thread Size:
0.500 inches
Semiconductor Material:
Germanium
Voltage Rating In Volts Per Characteristic:
-60.0 collector to base voltage, dc and -40.0 collector to emitter voltage, dc and -20.0 emitter to base voltage, dc
Power Rating Per Characteristic:
20.0 watts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnp
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
81349-mil-s-19500/89 government specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

No

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